CMOS Digital Integrated Circuits Silicon Monolithic

TC7PCI3412MT,TC7PCI3415MT

1. Functional Description

4 Differential Channel, 2:1 multiplexer/demultiplexer switch for PCI Express Gen3

2. General

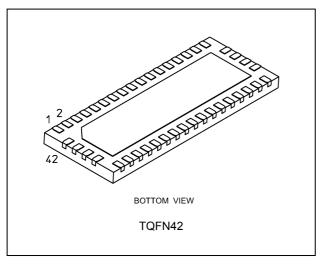
The TC7PCI3412MT and TC7PCI3415MT are 4 differential channel, 1-2 multiplexer/demultiplexer for PCI Express Gen3 (8Gbps), or other high-speed interface applications.

The An+/An- inputs is connected to the Bn+/Bn- or Cn+/Cn- outputs determined by the combination both the select input (SEL) and output enable (\overline{OE}) . When the output enable (\overline{OE}) input is held high-level, the switches are open (high-impedance state) with regardless the state of select inputs and reducing consumption current. All inputs are equipped with protection circuits against static discharge.

3. Features

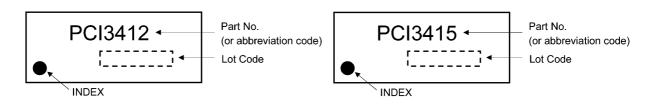
- (1) Operating voltage: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
- (2) Switch terminal ON-capacitance: $C_{\rm I/O}$ = 1.5 pF Switch On (typ.) @ $V_{\rm CC}$ = 3.3 V
- (3) ON resistance: $R_{ON} = 7.5 \Omega$ (typ.) @ $V_{CC} = 3.0 \text{ V}$, $V_{IS} = 0 \text{ V}$
- (4) -3dB Bandwidth: BW = 10 GHz (typ.) @ V_{CC} = 3.3 V
- (5) Insertion Loss: DDIL = -1 dB (typ.) @ V_{CC} = 3.3 V, f = 4 GHz
- (6) Off Isolation: DDOIRR = -20 dB (typ.) @ V_{CC} = 3.3 V, f = 4 GHz
- (7) Crosstalk: DDNEXT = -40 dB (typ.) @ V_{CC} = 3.3 V, f = 4 GHz
- (8) ESD performance: Machine model $\geq \pm 200$ V, Human body model $\geq \pm 2000$ V
- (9) Package: TQFN42

4. Packaging



5. Marking

TC7PCl3412MT TC7PCl3415MT



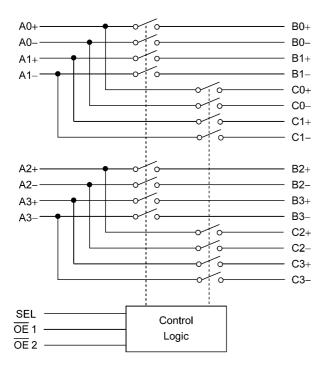


6. Pin Assignment

TC7PCI3412MT TC7PCI3415MT V_{CC} OE 1 V_{CC} GND GND VCC OE 1 VCC 42 41 40 39 42 41 40 39 B0+ GND 38 A0+ 38 **GND** 2 37 B0-2 37 A0+ A0-B0+ 3 A0-36 B1+ C0+ 3 36 B0-B1-GND 4 35 C0-35 GND 4 C0+ V_{CC} 5 34 A1+ 5 34 Vcc **B1**+ A1+ 6 33 C0-A1-6 33 7 C1+ A1-32 C1+ 7 32 B1-V_{CC} 8 C1-8 31 C1-31 Vcc SEL 9 SEL 30 Vcc V_{CC} 9 30 GND 10 29 B2+ A2+ 10 29 GND A2+ 11 B2-A2- 11 28 **B2**+ 28 A2- 12 27 B3+ C2+ 12 27 B2-В3-V_{CC} 13 26 C2- 13 26 Vcc **GND** 14 25 25 **GND** C2+ A3+ 14 A3+ 15 C2-24 A3- 15 24 B3+ A3- 16 23 C3+ C3+ 16 23 B3-**GND** 17 C3- 17 22 22 C3-**GND** 19 20 20 V_{CC} OE 2 V_{CC} GND GND VCC OE 2 VCC



7. Block Diagram



8. Principle of Operation

8.1. Truth Table

Inputs OE1	Inputs OE2	Inputs SEL	Function		
L		L	An+ port = Bn+ port, An- port = Bn- port	(n=0,1)	
L		Н	An+ port = Cn+ port, An- port = Cn- port	(n=0,1)	
Н	_	_	An, Bn, Cn port Disconnect	(n=0,1)	
_	L	L	An+ port = Bn+ port, An- port = Bn- port	(n=2,3)	
_	Ĺ	Н	An+ port = Cn+ port, An- port = Cn- port	(n=2,3)	
_	Н	_	An, Bn, Cn port Disconnect	(n=2,3)	

—: Don't care.



9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V_{CC}		-0.5 to 4.6	V
Input voltage (OE1, OE2, SEL)	V _{IN}		-0.5 to 4.6	V
Switch I/O voltage	V_S		-0.5 to V _{CC} +0.5	V
Switch I/O current	I _S		50	mA
Power dissipation	P_{D}		500	mW
V _{CC} /ground current	I _{CC} /I _{GND}		±50	mA
Storage temperature	T _{stg}		-55 to 125	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

10. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		3.0 to 3.6	V
Input voltage (OE1, OE2, SEL)	V _{IN}		0 to 3.6	V
Switch I/O voltage	V _S		0 to V _{CC}	V
Operating temperature	T _{opr}		-40 to 85	°C
Input rise time	dt/dv	·	0 to 10	ns/V
Input fall time	dt/dv		0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused control inputs must be tied to either V_{CC} or GND.

11. Electrical Characteristics

11.1. DC Characteristics (Note) (Unless otherwise specified, Ta = -40 to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage (OE1, OE2, SEL)	V _{IH}		_	3.0 to 3.6	0.65 × V _{CC}	_	_	V
Low-level input voltage (OE1, OE2, SEL)	V _{IL}		_	3.0 to 3.6			0.35 × V _{CC}	V
Input leakage current (OE1, OE2, SEL)	I _{IN}		V _{IN} = 0 to 3.6 V	3.0 to 3.6			±1	μА
Switch OFF-state leakage current	I _{SZ}		$\frac{V_{IS} = 0 \text{ to } V_{CC},}{OE1 = OE2 = V_{CC}}$	3.0 to 3.6		_	±1	μА
ON-resistance	R _{ON}	(Note 1)	$V_{IS} = 0 \text{ V}, I_{IS} = 30 \text{ mA}$	3.0	_	7.5	11.5	Ω
	R _{ON}	(Note 1)	V _{IS} = 1.2 V, I _{IS} = 30 mA	3.0	_	8.5	13.5	Ω
Difference of ON-resistance between switches (bit to bit)	ΔR _{ON}	(Note 1)	V _{IS} = 0 V, 1.2 V, I _{IS} = 15 mA	3.0	_	0.1	_	Ω
ON-resistance flatness	R _{ON(flat)}	(Note 1)	V _{IS} = 0 V to 1.2 V, I _{IS} = 15 mA	3.0	_	1	_	Ω
Quiescent supply current	I _{CC}		$\frac{V_{IN}}{OE1} = V_{CC}$ or GND, $OE1 = OE2 = V_{CC}$	3.6	_	_	1	μА
Quiescent supply current	I _{CC}		$V_{IN} = V_{CC}$ or GND, $\overline{OE1} = \overline{OE2} = \overline{GND}$	3.6	_	400	800	μА

Note : All typical values are at $T_a = 25$ °C.

Note 1: ON-resistance is measured by measuring the voltage drop across the switch at the indicated current.



11.2. AC Characteristics (Note) (Unless otherwise specified, Ta = -40 to 85 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} / t _{PHL}	(Note 1)	$C_L = 5 \text{ pF}$ See Fig. 12.1	3.3 ± 0.3	_	0.1	_	ns
Turn-ON time (SEL to Output)	t _{on}		R_L = 50 Ω , C_L = 5 pF See Fig. 12.2	3.3 ± 0.3	_	10	15	ns
Turn-ON time (OE to Output)	t _{on}		R_L = 50 Ω , C_L = 5 pF See Fig. 12.2	3.3 ± 0.3	_	37	50	μS
Turn-OFF time (SEL to Output)	t _{off}		R_L = 50 Ω , C_L = 5 pF See Fig. 12.2	3.3 ± 0.3	_	3.5	5	ns
Turn-OFF time (OE to Output)	t _{off}		R_L = 50 Ω , C_L = 5 pF See Fig. 12.2	3.3 ± 0.3	_	5	6.5	ns
Break before make	TBBM		R_L = 50 Ω , C_L = 5 pF See Fig. 12.3	3.3 ± 0.3	3	_	9	ns
Output skew (bit to bit)	t _{SK(b)}	(Note 1)	C _L = 5 pF See Fig. 12.4	3.3 ± 0.3	_	5	_	ps
Output skew (channel to channel)	t _{SK(CH)}	(Note 1)	$C_L = 5 \text{ pF}$ See Fig. 12.5	3.3 ± 0.3	_	10	_	ps
Differential OFF isolation	DDOIRR	(Note 1)	R_T = 50 Ω , f = 4 GHz See Fig. 12.6	3.3 ± 0.3	_	-20	_	dB
Differential Near-end crosstalk	DDNEXT	(Note 1)	R_T = 50 Ω , f = 4 GHz See Fig. 12.7	3.3 ± 0.3	_	-40	_	dB
Differential return loss	DDRL	(Note 1)	R_T = 50 Ω , f = 4 GHz See Fig. 12.8	3.3 ± 0.3	_	-20	_	dB
Differential insertion loss	DDIL	(Note 1)	R_T = 50 Ω , f = 4 GHz See Fig. 12.8	3.3 ± 0.3		-1	_	dB
-3dB Bandwidth	BW	(Note 1)	R_T = 50 Ω , C_L = 0 pF See Fig. 12.8	3.3 ± 0.3		10	_	GHz

Note : All typical values are at T_a = 25 °C.

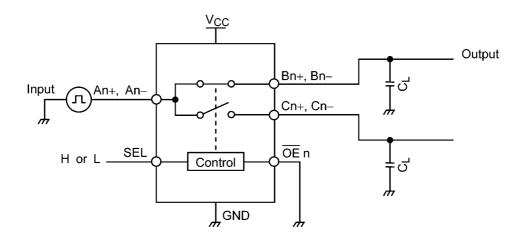
Note 1: This parameter is guaranteed by design.

11.3. Capacitive Characteristics (Note) (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance (OE1, OE2, SEL)	C _{IN}		V _{IN} = 0 V	3.3	3	pF
Switch terminal OFF-capacitance (An+, An-)	C _{I/O}		$\overline{OE}1 = \overline{OE}2 = V_{CC}, V_{IS} = 0 V$	3.3	8.0	pF
Switch terminal OFF-capacitance (Bn+, Bn-, Cn+, Cn-)			$\overline{OE}1 = \overline{OE}2 = V_{CC}, V_{IS} = 0 V$	3.3	0.5	pF
Switch terminal ON-capacitance	C _{I/O}		$\overline{OE}1 = \overline{OE}2 = GND, V_{IS} = 0 V$	3.3	1.5	pF

Note: Parameter guaranteed by design.

12. AC Electrical Test Circuit (Fig)



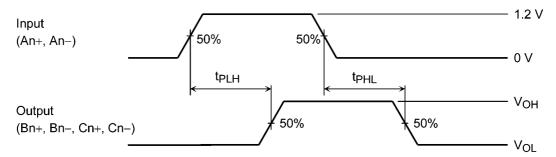
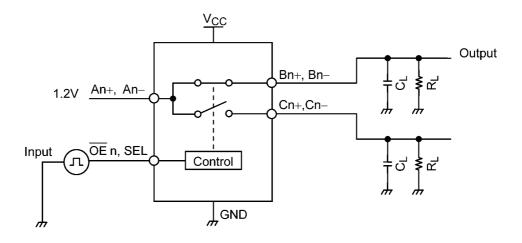


Fig. 12.1 Propagation delay time



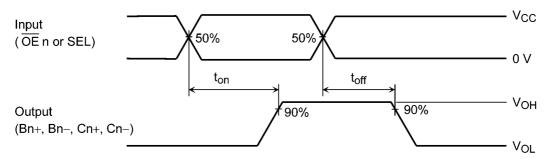


Fig. 12.2 Turn-ON and Turn-OFF time

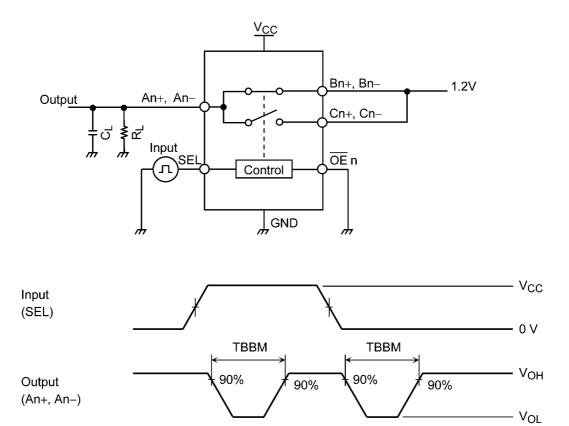
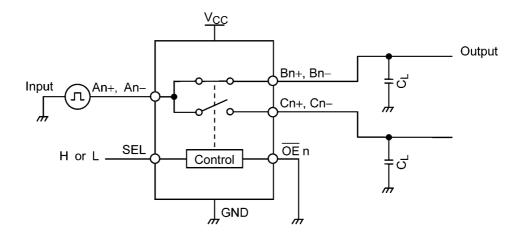


Fig. 12.3 Break before make



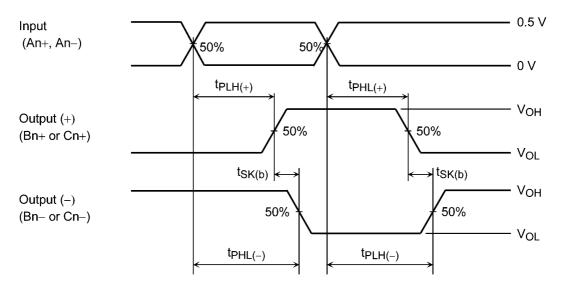


Fig. 12.4 Output skew (bit to bit)

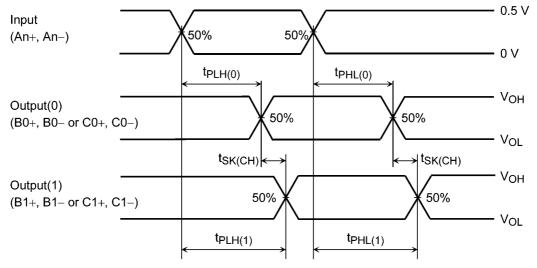


Fig. 12.5 Output skew (channel to channel)

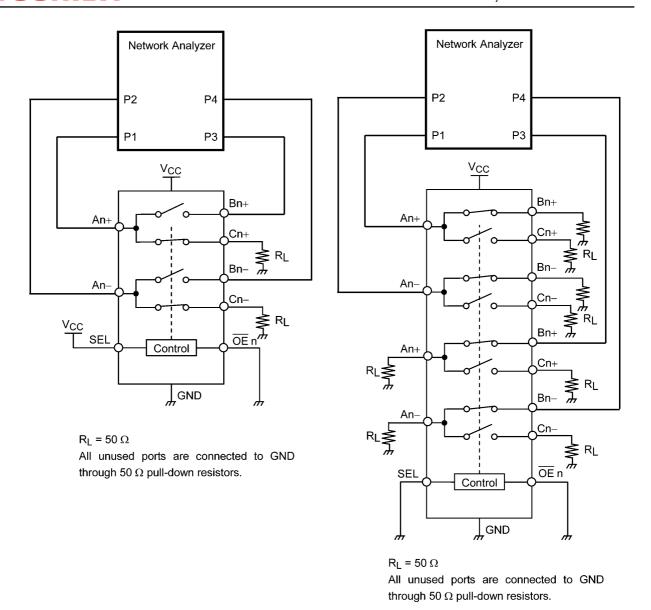


Fig. 12.6 Differential OFF isolation

Fig. 12.7 Differential Near-end crosstalk

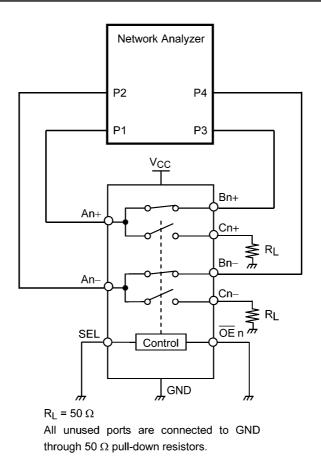
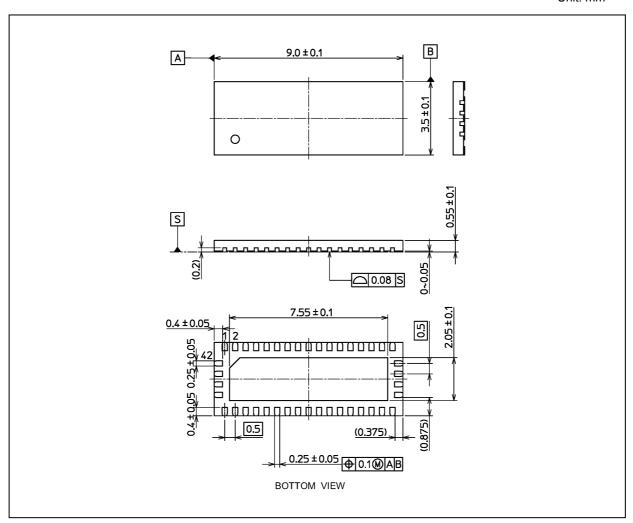


Fig. 12.8 Differential return loss, Differential insertion loss, -3dB Bandwidth



Package Dimensions

Unit: mm



Weight: 0.06 g (typ.)

Package Name(s)
TOSHIBA: P-UQFN42-0409-0.50-001
Nickname: TQFN42



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